

300mA, Micropower, VLDO Linear Regulator UM165xx SOT23-3

General Description

The UM165xx series are VLDO (very low dropout) linear regulators designed for low power portable applications. Maximum dropout is just 90mV at the load current of 150mA. The internal P-channel MOSFET pass transistor requires no base current, allowing the device to draw only 100µA during normal operation at the maximum load current of 300mA.

Other features include high output voltage accuracy, excellent transient response, under voltage lockout, stability with ultralow ESR ceramic capacitors as small as 1μ F, reverse-battery protection, short-circuit and thermal overload protection and output current limiting.

The UM165xx series are available in a low profile SOT23-3 package.

Applications

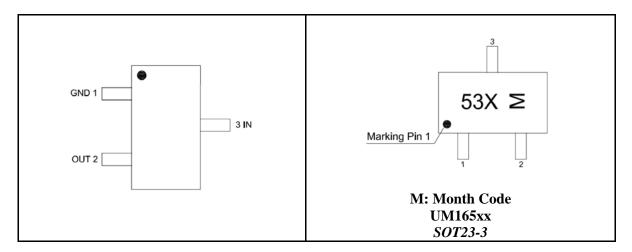
Features

- Bluetooth/802.11 Cards
- PDAs and Notebook Computers
- Portable Instruments and Battery-Powered Systems
- Cellular Phones

- Very Low Dropout: 90mV (Max) at 150mA
- Maximum Input Voltage: 6.0V
- $\pm 2\%$ Voltage Accuracy at 150mA
- Fast Transient Response
- Under Voltage Lockout
- Fixed Output Voltage: 3.3V/2.8V
- Output Current Limit
- Reverse-Battery Protection
- No Protection Diodes Needed
- Stable with 1µF Output Capacitor
- Short-Circuit and Thermal Overload Protection
- Low Profile SOT23-3 Package

Pin Configurations







Ordering Information

Part Number	Output Voltage	Packaging Type	Marking Code	Shipping Qty
UM16528	2.8V	SOT23-3	53Q	3000pcs/7Inch
UM16533	3.3V	50125-5	53U	Tape & Reel

Pin Description

Pin Number	Symbol	Function
1	GND	Ground
2	OUT	Voltage Regulated Output
3	IN	Power Supply

Absolute Maximum Ratings (Note 1)

Symbol	Parameter	Value	Unit	
V _{IN}	Supply Voltage on IN Pin	-7.5 to +7.5	V	
V _{OUT}	Voltage on OUT Pin	-0.3 to +7.5	V	
	Output Short-Circuit Duration	Indefinite		
TJ	Operating Junction Temperature (Note 2, 3)	-40 to +125	°C	
T _{STG}	Storage Temperature Range	-65 to +150	°C	
$T_{\rm L}$	Lead Temperature for Soldering 10 Seconds	+300	°C	

Note 1: Absolute Maximum Ratings are those values beyond which the life of a device may be impaired.

- Note 2: The UM165xx is tested and specified under pulse load conditions such that T_J≈T_A. The device is guaranteed to meet performance specifications from 0°C to 70°C. Specifications over the -40°C to 125°C operating junction temperature range are assured by design, characterization and correlation with statistical process controls.
- Note 3: This IC includes overtemperature protection that is intended to protect the device during momentary overload conditions. Junction temperature will exceed 125°C when overtemperature protection is active. Continuous operation above the specified maximum operating junction temperature may impair device reliability.



Electrical Characteristics

Symbol	Parameter	Test Conditions		Min	Тур	Max	Unit	
V _{IN}	Input Voltage Range			V _{OUT} + V _{DROP}		6.0	V	
V _{UVLO1} (Note 1)	Input Under Voltage Lockout	V _{IN} Falling		2.0		2.6	V	
V _{UVLO2} (Note 2)	Input Under Voltage Lockout	V _{IN} F	alling	2.1		2.3	v	
т	Operating Quiescent	I _{OUT} =	=0mA		90			
I _Q	Current	I _{OUT} =3	300mA		100		μA	
	ESD Rating	Human B	ody Mode	2			kV	
I _{OUT}	Output Current			300			mA	
			_T ≤150mA, -25°C	-1		+1		
	Output Voltage Accuracy		$1mA \le I_{OUT} \le 150mA,$ T _A =-40°C to +85°C			+2	%	
		$\frac{1\text{mA} \le I_{\text{OUT}} \le 300\text{mA}}{T_{\text{A}} = -40^{\circ}\text{C to} + 85^{\circ}\text{C}}$		-2.5		+2.5		
ΔV_{DO}	Dropout Voltage	I _{OUT} =]	I _{OUT} =150mA			90	mV	
I _{LIMT}	Output Current Limit	V _{IN} ≥	V _{IN} ≥2.5V				mA	
	Input Reverse Leakage Current (OUT to IN Leakage Current)		V _{OUT} =5.5V Active		0.01	1.5	μΑ	
T _{SHDN}	Thermal-Shutdown Temperature				160		°C	
ΔT_{SHDN}	Thermal-Shutdown Hysteresis				20		°C	
	Line Regulation		V _{IN} ≤V _{OUT} +2V 10mA		0.09		%/V	
	Load Regulation	V _{IN} =V	_{OUT} +1V _T ≤150mA		0.2		%	
			f=100Hz		70			
DCDD	Power Supply Ripple	V _{IN} =V _{OUT} +1V	f=1kHz		65		dB	
PSRR	Rejection	I _{OUT} =100mA	f=10kHz		50		uБ	
		f=100kHz			40			

Note 1: V_{UVLO1} is measured for devices with $V_{OUT} \ge 1.8V$. Note 2: V_{UVLO2} is measured for devices with $V_{OUT} \le 1.5V$.

Note 3: ΔV_{DO} just define for device with $V_{OUT} \ge 2.5V$.



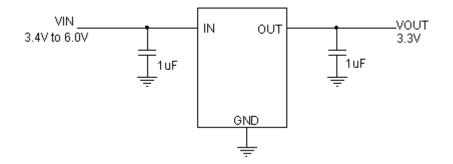
Pin Function

GND (Pin1): Ground and Heat Sink. Solder to a ground plane or large pad to maximize heat dissipation.

OUT (Pin 2): Voltage Regulated Output. The OUT pin supplies power to the load. A minimum output capacitor of 1μ F is required to ensure stability. Larger output capacitors may be required for applications with large transient loads to limit peak voltage transients. See the Applications Information section for more information on output capacitance.

IN (**Pin 3**): Power for UM165xx and Load. Power is supplied to the devices through the IN pin. The IN pin should be locally bypassed to ground if the UM165xx series are more than a few inches away from another source of bulk capacitance. In general, the output impedance of a battery rises with frequency, so it is usually advisable to include an input bypass capacitor in battery-powered circuits. A capacitor in the range of 0.1μ F to 1μ F is usually sufficient. The UM165xx series are designed to withstand reverse voltages on the IN pin with respect to both ground and the output pin. In the case of a reversed input, which can happen if a battery is plugged in backwards, the UM165xx will act as if there is a large resistor in series with its input with only a small amount of current flow.

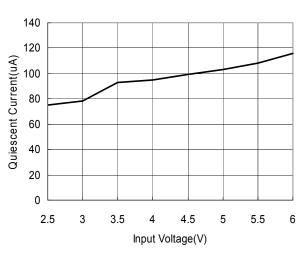
Typical Application Circuit



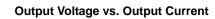


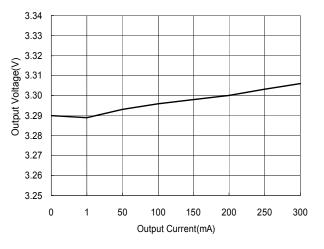


Typical Performance Characteristics

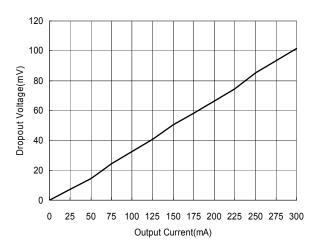


Quiescent Current vs. Input Voltage

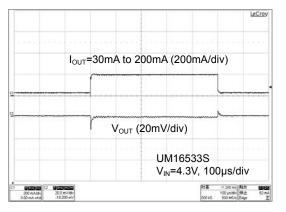




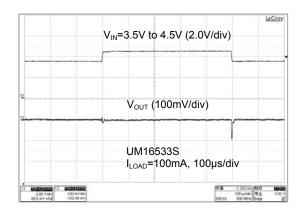
Dropout Voltage vs. Output Current







Line Transient Response

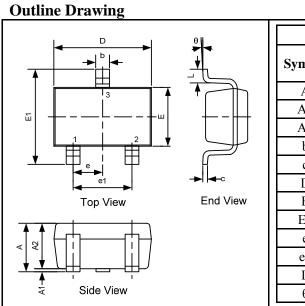






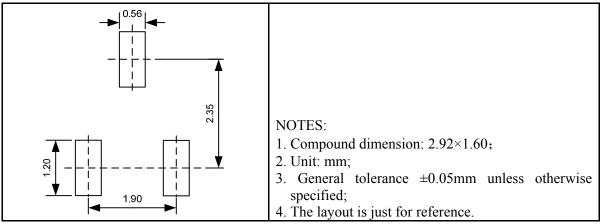
Package Information

UM165xx: SOT23-3

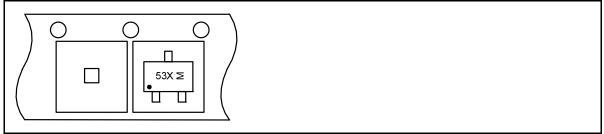


		DIM	ENSIC	NS		
S-mak al	MILLIMETERS			INCHES		
Symbol	Min	Тур	Max	Min	Тур	Max
А	1.013	1.15	1.40	0.040	0.045	0.055
A1	0.00	0.05	0.10	0.000	0.002	0.004
A2	1.00	1.10	1.30	0.039	0.043	0.051
b	0.30	-	0.50	0.012	-	0.020
c	0.10	0.15	0.20	0.004	0.006	0.008
D	2.82	-	3.10	0.111	-	0.122
Е	1.50	1.60	1.70	0.059	0.063	0.067
E1	2.60	2.80	3.00	0.102	0.110	0.118
e	0.95REF			C	.037RE	F
e1	1.90REF		0.075REF			
L	0.30	-	0.60	0.012	-	0.024
θ	0°	-	8°	0°	-	8°

Land Pattern



Tape and Reel Orientation





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